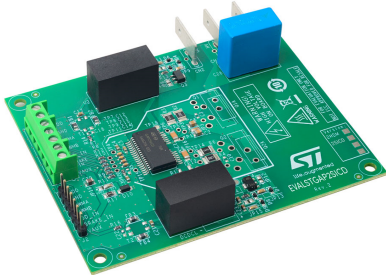


Demonstration board for EVALSTGAP2SICD isolated 4 A half-bridge gate driver



Features

- **Board**
 - High voltage rail up to 1200 V
 - Negative gate driving
 - On-board isolated DC-DC converters to supply high-side and low-side gate drivers, fed by VAUX = 5 V, with 5.2 kV maximum isolation
 - VDD logic supplied by on-board generated 3.3 V or VAUX = 5V
 - Easy jumper selection of driving voltage configuration: +17/0 V; +17/-3 V; +19/0 V; +19/-3 V;
- **Device**
 - Driver current capability: 4 A source/sink @ 25°C
 - 4 A Miller CLAMP
 - Short propagation delay: 75 ns
 - UVLO function
 - Configurable interlocking function
 - Dedicated SD and BRAKE pins
 - Gate driving voltage up to 26 V
 - 3.3 V, 5 V TTL/CMOS inputs with hysteresis
 - Temperature shutdown protection
 - Standby function

Product status link

[EVALSTGAP2SICD](#)

Description

The **EVALSTGAP2SICD** is an half bridge evaluation board designed to evaluate the STGAP2SiCD isolated dual gate driver.

The gate driver is characterized by 4 A current capability and rail-to-rail outputs, making the device suitable also for high power applications such as motor drivers in industrial applications equipped with SiC power switches.

The device integrates protection functions: dedicated SD and BRAKE pins are available, UVLO and thermal shutdown are included to easily design high reliability systems, and the interlocking function prevents outputs from being high at the same time.

The device allows implementing negative gate driving, and the on-board isolated DC-DC converters allows working with optimized driving voltage for SiC MOSFETs.

The EVALSTGAP2SICD board allows evaluating all the STGAP2SICD features while driving a half-bridge power stage with voltage rating up to 1200 V in TO-220 or TO-247 package.

The board allows easily selecting and modifying the values of relevant external components in order to ease driver performance evaluation under different applicative conditions and fine pre-tuning of final application components.

1 Schematic diagram

Figure 1. EVALSTGAP2SICD schematic – gate driver

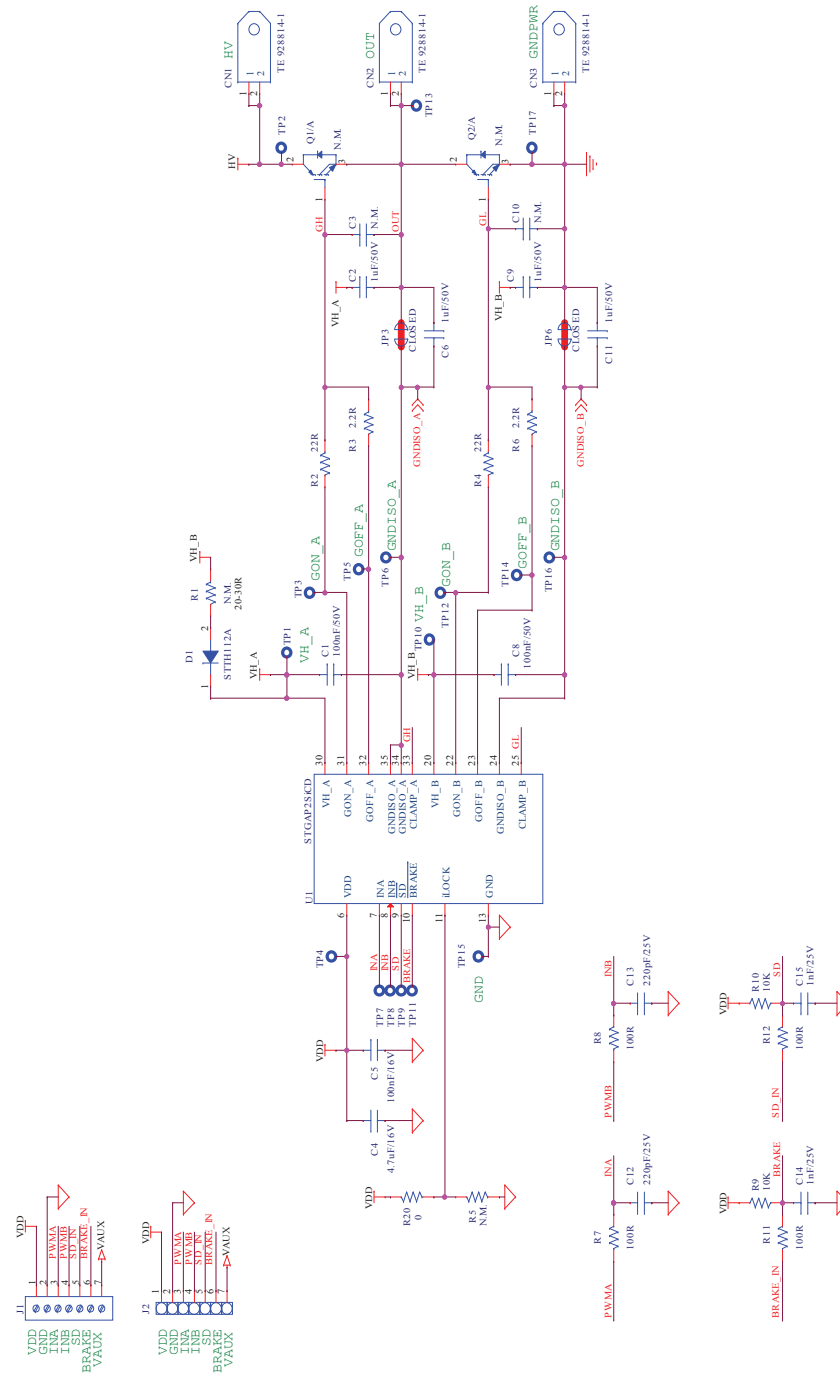
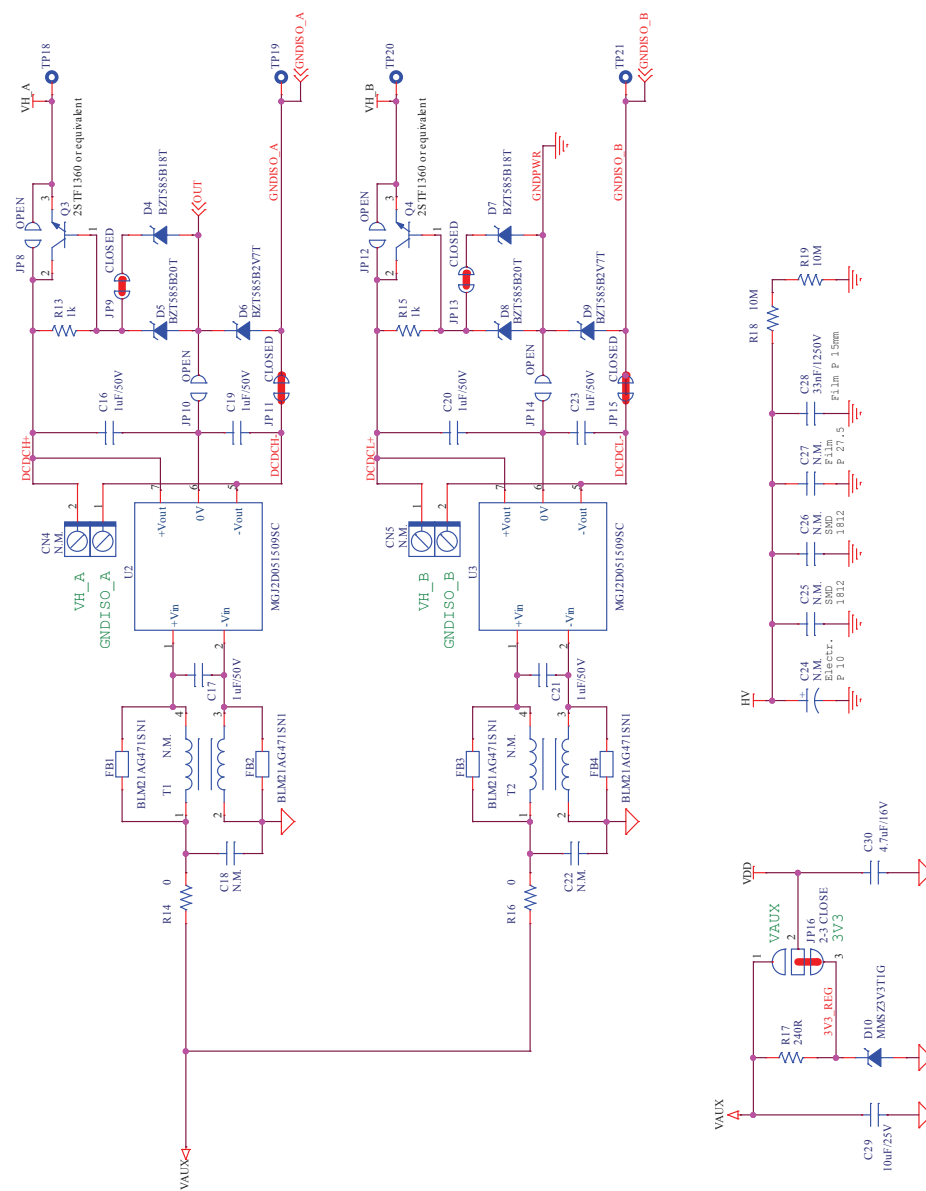


Figure 2. EVALSTGAP2SICD circuit schematic – supply, connectors and decoupling


2 Bill of material

Table 1. EVALSTGAP2SICD - Bill of Material

Part Reference	Part value	Part description
CN1, CN2, CN3	TE 928814-1	Tab FASTON 250 Horizontal, 5.08 mm
CN4, CN5	N.M.	Connector terminal block T.H. 2 POS 5.08 mm
C1, C8	100 nF / 50 V	Ceramic capacitor, SMT 1206
C2, C6, C9, C11	1 μ F / 50 V	Ceramic capacitor, SMT 0805
C3, C10, C18, C22	N.M.	Ceramic capacitor, SMT 0603
C4, C30	4.7 μ F / 16 V	Ceramic capacitor, SMT 0603
C5	100 nF / 16 V	Ceramic capacitor, SMT 0603
C12, C13	220 pF / 25 V	Ceramic capacitor, SMT 0603
C14, C15	1 nF / 25 V	Ceramic capacitor, SMT 0603
C16, C17, C19, C20, C21, C23	1 μ F / 50 V	Ceramic capacitor, SMT 0603
C24	N.M.	THT electrolytic capacitor, P 10 mm
C25, C26	N.M.	Ceramic capacitor, SMT 1812
C27	N.M.	Film capacitor, P 27.5 mm
C28	33 nF / 1250 V	Film capacitor, P 15 mm
C29	10 μ F / 25 V	Ceramic capacitor, SMT 0805
D1	STTH112A	High voltage ultrafast rectifier, SMA
D4, D7	BTZT585B18T	Surface mount precision Zener diode, SOD523
D5, D8	BZT585B20T	Surface mount precision Zener diode, SOD523
D6, D9	BZT585B2V7T	Surface mount precision Zener diode, SOD523
D10	MMSZ3V3T1G	Zener voltage regulator 500 mW, SOD-123
FB1, FB2, FB3, FB4	BLM21AG471SN1	Ferrite beads, SMT 0805
JP3, JP6, JP9, JP11, JP13, JP15	Closed	SMT jumper
JP8, JP10, JP12, JP14	Open	SMT jumper
JP16	Closed 2-3	SMT jumper
J1	WE691243110007 or similar	Connector terminal block T.H. 7 POS 3.5 mm
J2	Pin strip	Strip connector 7 pos, 2.54 mm
Q1, Q2	N.M.	N-channel IGBT or MOSFET up to 1700 V, TO-247
Q1A, Q2A	N.M.	N-channel IGBT or MOSFET up to 1700 V, TO-220
Q3, Q4	2STF1360	Low voltage fast-switching NPN power transistors, SOT-89
R1	N.M.	Chip resistor, SMT 1206
R2, R4	22 Ω	Chip resistor, SMT 1210
R3, R6	2.2 Ω	Chip resistor, SMT 1210
R5	N.M.	Chip resistor, SMT 0603
R7, R8, R11, R12	100 Ω	Chip resistor, SMT 0603
R9, R10	10 k Ω	Chip resistor, SMT 0603
R13, R15	1 k Ω	Chip resistor, SMT 0603
R14, R16, R20	0 Ω	Chip resistor, SMT 0603
R17	240 Ω	Chip resistor, SMT 0805
R18,R19	10 M Ω	Chip resistor, SMT 1206

Part Reference	Part value	Part description
TP1, TP2, TP3, TP4, TP5, TP6, TP7, TP8, TP9, TP10, TP11, TP12, TP13, TP14, TP15, TP16, TP17	N.M.	Loop test point, THT
TP18, TP19, TP20, TP21	N.M.	Pad test point, SMD 1.5 mm
T1, T2	N.M.	Common mode choke, SMD 4.7x4.5 mm
U1	STGAP2SICD	Galvanically isolated 4 A dual gate driver for SiC MOSFETs, SO-36W
U2, U3	MGJ2D051509SC	Murata 5.2 kVDC Isolated 2W Gate Drive DC/DC converters

3 Layout and component placements

Figure 3. EVALSTGAP2SICD – Layout (component placement top view)

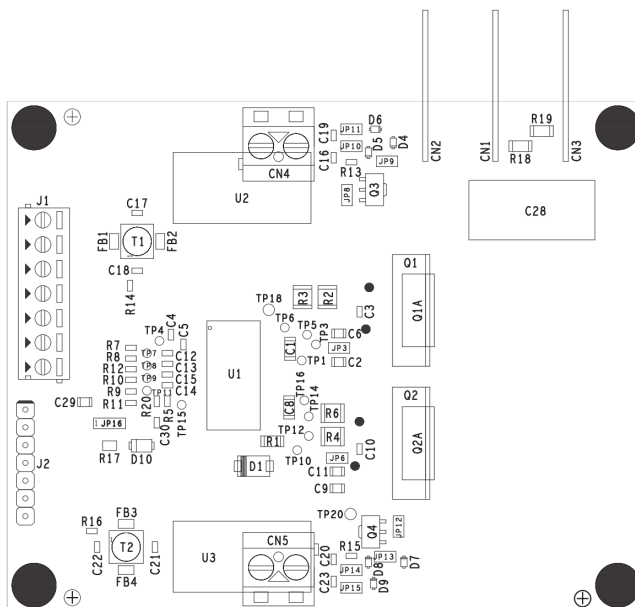


Figure 4. EVALSTGAP2SICD – Layout (component placement bottom view)

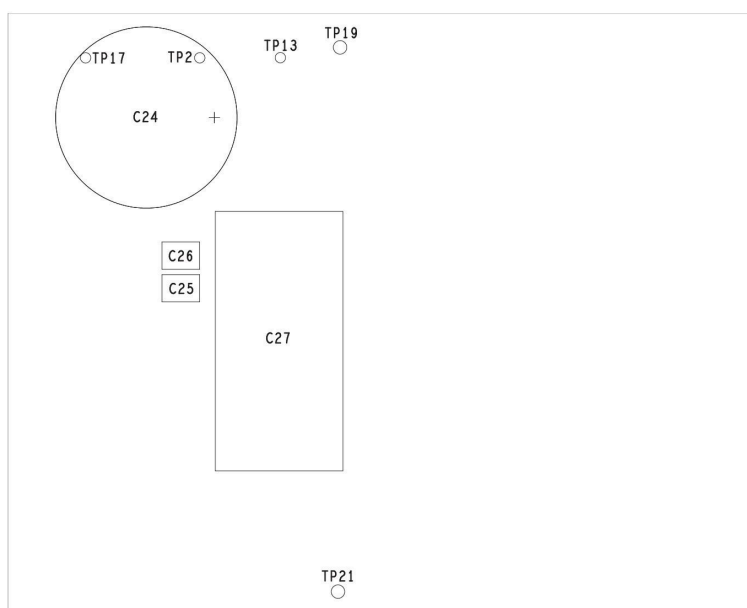


Figure 5. EVALSTGAP2SICD – Layout (top layer)

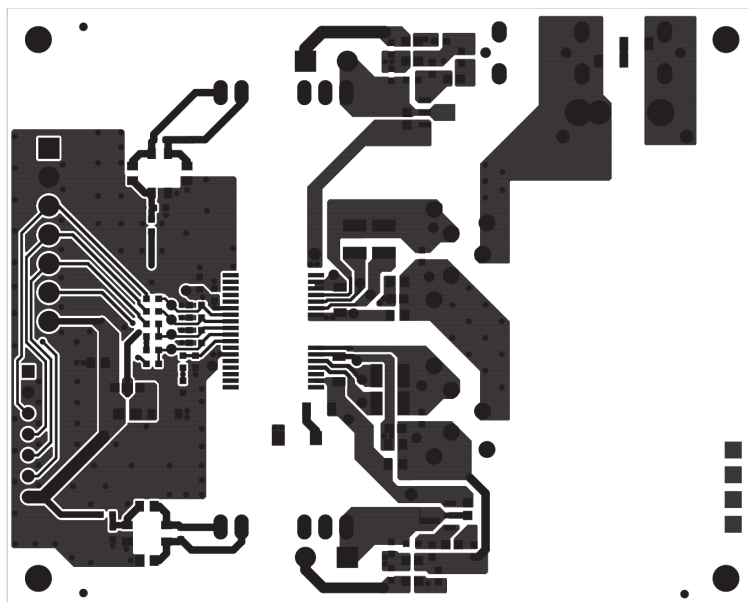
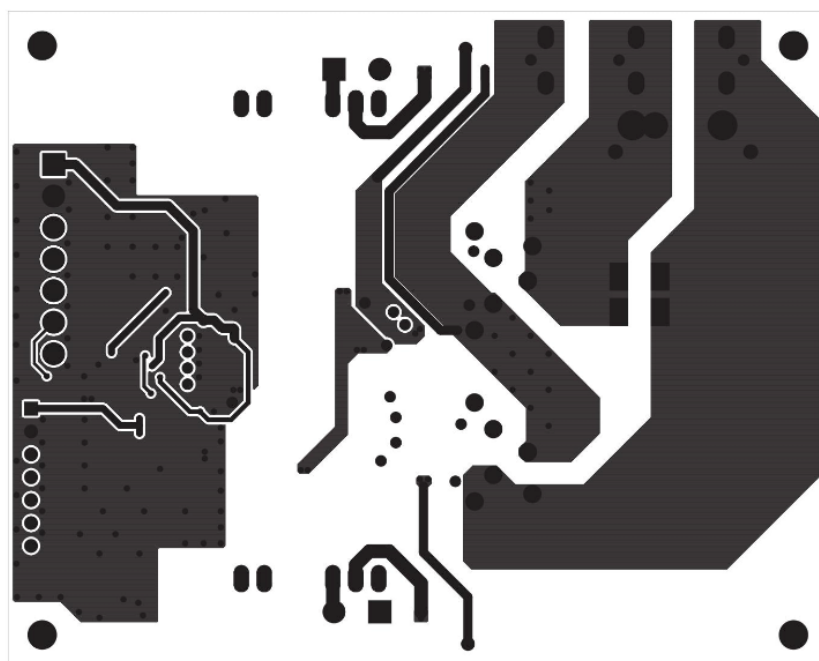


Figure 6. EVALSTGAP2SICD – Layout (bottom layer)



Revision history

Table 2. Document revision history

Date	Version	Changes
29-Oct-2021	1	Initial release.

Contents

1	Schematic diagram	2
2	Bill of material	4
3	Layout and component placements	6
	Revision history	8
	Contents	9
	List of tables	10
	List of figures.....	11



List of tables

Table 1. EVALSTGAP2SICD - Bill of Material. 4

Table 2. Document revision history 8

List of figures

Figure 1.	EVALSTGAP2SICD schematic – gate driver.	2
Figure 2.	EVALSTGAP2SICD circuit schematic – supply, connectors and decoupling	3
Figure 3.	EVALSTGAP2SICD – Layout (component placement top view).	6
Figure 4.	EVALSTGAP2SICD – Layout (component placement bottom view)	6
Figure 5.	EVALSTGAP2SICD – Layout (top layer)	7
Figure 6.	EVALSTGAP2SICD – Layout (bottom layer)	7

IMPORTANT NOTICE – PLEASE READ CAREFULLY

STMicroelectronics NV and its subsidiaries ("ST") reserve the right to make changes, corrections, enhancements, modifications, and improvements to ST products and/or to this document at any time without notice. Purchasers should obtain the latest relevant information on ST products before placing orders. ST products are sold pursuant to ST's terms and conditions of sale in place at the time of order acknowledgement.

Purchasers are solely responsible for the choice, selection, and use of ST products and ST assumes no liability for application assistance or the design of Purchasers' products.

No license, express or implied, to any intellectual property right is granted by ST herein.

Resale of ST products with provisions different from the information set forth herein shall void any warranty granted by ST for such product.

ST and the ST logo are trademarks of ST. For additional information about ST trademarks, please refer to www.st.com/trademarks. All other product or service names are the property of their respective owners.

Information in this document supersedes and replaces information previously supplied in any prior versions of this document.

© 2021 STMicroelectronics – All rights reserved

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

[STMicroelectronics:](#)

[EVALSTGAP2SICD](#)